

SiC Schottky Barrier Diode

V_R	1200V		
I _F	10A		
Q_C	34nC		

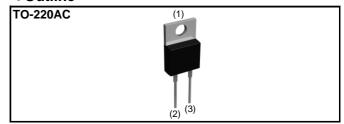
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

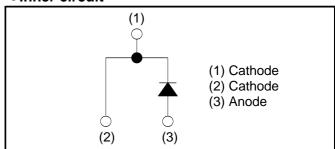
Construction

Silicon carbide epitaxial planer type

Outline



●Inner circuit



Packaging specifications

			
Type	Packaging	Tube	
	Reel size (mm)	-	
	Tape width (mm)	-	
	Basic ordering unit (pcs)	50	
	Taping code	-	
	Marking	SCS110KG	

● Absolute maximum ratings (Tj = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	1200	V	
Reverse voltage (DC)	V_R	1200	V	
Continuous forward current	I _F	10* ¹	А	
Course as a secretify a few years as a summer.		45* ²	А	
Surge no repetitive forward current	I _{FSM}	190* ³	А	
Repetitive peak forward current	I _{FRM}	38*4	А	
Total power dissipation	P _D	100* ⁵	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	-55 to +175	°C	
Thermal resistance, junction to case	Rth(j-c)	1.4	°C/W	

^{*1} Tc=132°C *2 PW=8.3ms sinusoidal,Tj=25°C

^{*3} PW=10µs square,Tj=25°C *4 Tc=100°C,Tj=150°C,Duty cycle=10% *5 Tc=25°C

●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter			Min.	Тур.	Max.	Offic
DC blocking voltage	V_{DC}	$I_R = 0.2 \text{mA}$	1200	-	-	V
Forward voltage	V _F	I _F =10A,Tj=25°C	-	1.5	1.75	V
		I _F =10A,Tj=175°C	-	2.0	-	V
Reverse current	I _R	V _R =1200V,Tj=25°C	-	10	200	μΑ
		V _R =1200V,Tj=175°C	-	120	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	650	-	pF
		V _R =800V,f=1MHz	-	50	-	pF
Total capacitive charge	Qc	V _R =800V,di/dt=500A/μs	-	34	-	nC
Switching time	tc	V _R =800V,di/dt=500A/μs	ı	16	-	ns

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

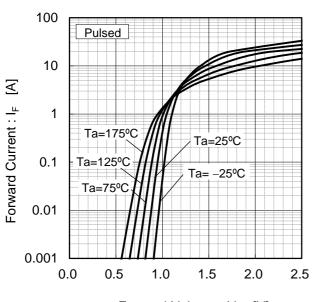
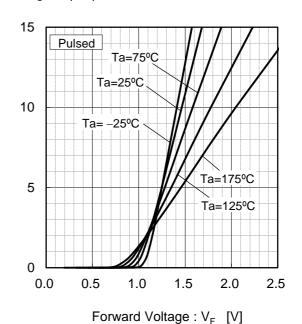


Fig.2 V_F - I_F Characteristics

Forward Current: IF [A]



Forward Voltage : V_F [V]

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Fig.3 V_R - I_R Characteristics

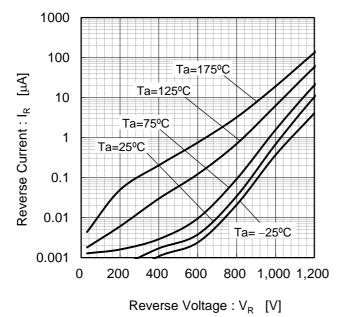
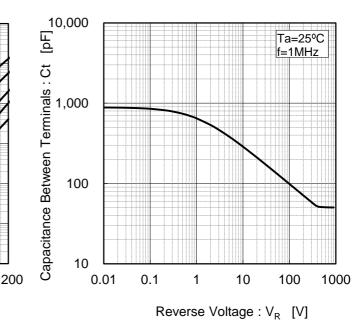


Fig.4 V_R-Ct Characteristics



•Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

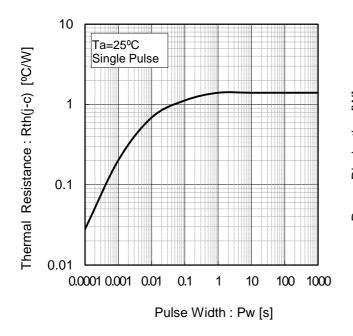
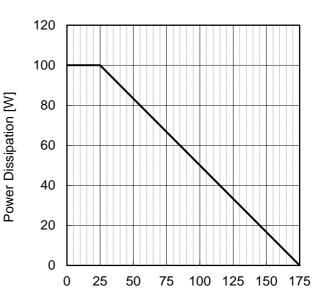


Fig.6 Power Dissipation



Case Temperature : Tc [°C]

Fig.7 Derating Curve Ip-Tc

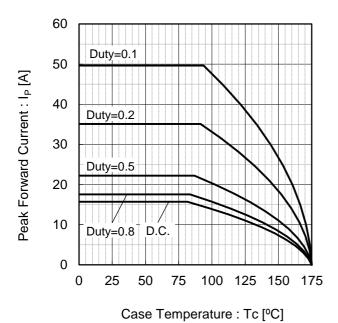
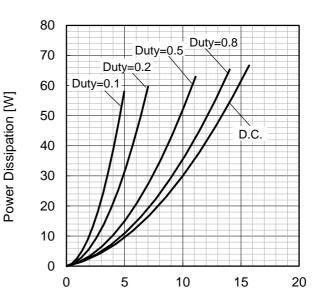


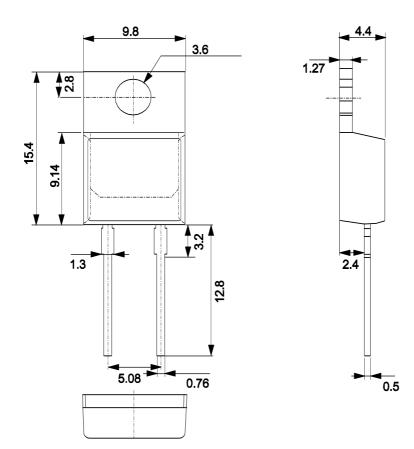
Fig.8 Io-Pf Characteristics



Average Rectified Forward Current : Io [A]

●Dimensions (Unit:mm)

TO-220AC



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